

Continental Device India Pvt. Limited An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



## NPN-POWER TRANSISTOR



BDY20 TO-3 Metal Can Package

## **ABSOLUTE MAXIMUM RATING**

PARAMETER	SYMBOL	VALUE	UNITS
Collector-base voltage (open emitter)	V <sub>CBO</sub>	100	V
Collector-base voltage (open base)	$V_{ceo}$	60	V
Collector-emitter voltage (R <sub>BE</sub> =100Ω)	$V_{_{CER}}$	70	V
Emitter-base voltage (open collector)	V <sub>EBO</sub>	7	V
Collector current	I <sub>c</sub>	15	A
Base current	I <sub>B</sub>	7	A
Total power dissipation up to T <sub>c</sub> =25°C	P <sub>tot</sub>	115	W
Derate above 25°C		0.657	W/ºC
Junction temperature	TJ	200	°C
Storage temperature	T <sub>stg</sub>	-65 to 200	°C

### THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNITS
from junction to case	R <sub>th J-C</sub>	1.52	°C/W





# **ELECTRICAL CHARACTERISTICS** ( $T_A$ =25°C unless otherwise specified)

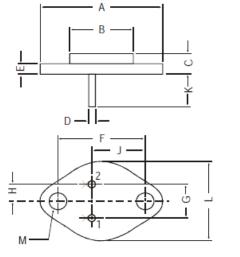
PARAMETER	SYMBOL	TEST CONDITIONS	VALUE		UNITS	
PARAIVIETER	STWBUL	TEST CONDITIONS	MIN	MAX	011113	
Collector-emitter cut-off current	I <sub>CEO</sub>	V <sub>CE</sub> =30V, I <sub>B</sub> =0	-	0.7	mA	
		V <sub>CE</sub> =100V, V <sub>BE(off)</sub> =1.5V	-	1	mA	
Collector cut-off current	I <sub>CEV</sub>	V <sub>CE</sub> =100V, V <sub>BE(off)</sub> =1.5V, T <sub>C</sub> =150°C	-	5	mA	
Emitter cut-off current	Ι <sub>ΕΒΟ</sub>	I <sub>C</sub> =0, V <sub>EB</sub> =7V	-	5	mA	
Collector -emitter sustaining voltage	$V_{CEO(sus)}^{*}$	I <sub>c</sub> =0.2A, I <sub>B</sub> =0	60	-	V	
Collector-base voltage	$V_{_{CBO}}$	I <sub>c</sub> =1mA, I <sub>E</sub> =0	100	-	V	
Emitter-base voltage	$V_{EBO}$	I <sub>E</sub> =1mA, I <sub>C</sub> =0	7	-	V	
Collector-emitter	V_cesat	I <sub>c</sub> = 4 A, I <sub>B</sub> = 0.4 A	-	1.1	V	
saturation voltage	♥ CEsat	I <sub>C</sub> = 10 A, I <sub>B</sub> = 3.3 A	-	3.0	V	
Base emitter on voltage	$V_{BE(on)}^{*}$	$I_{c}$ = 4A , $V_{ce}$ = 4V	-	1.5	V	
	h *	I <sub>C</sub> = 4A , V <sub>CE</sub> = 4V	20	70		
D.C. Current gain	h <sub>FE</sub> *	I <sub>C</sub> = 10A , V <sub>CE</sub> = 4V	5	-		
Small signal current gain	h <sub>fe</sub>	I <sub>c</sub> = 1 A, V <sub>ce</sub> = 4V, f=1KHz	15	120		
Transition frequency	$f_{T}$	I <sub>c</sub> = 0.5 A, V <sub>CE</sub> = 10V, f=1MHz	2.5	-	MHz	

\* Pulse test: pulse width  $\leq$  300 µs; duty cycle  $\leq$  2%



Continental Device India Pvt. Limited An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





#### TO-3 Metal Can Package

	DIM	MIN.	MAX.
	Α	_	39.37
	В	_	22.22
	С	6.35	8.50
	D	0.96	1.09
	Ε	_	1.77
	F	29.90	30.40
E	G	10.69	11.18
⊒.	Н	5.20	5.72
ions	J	16.64	17.15
ens	К	11.15	12.25
Al dimensions in mm.	L	_	26.67
Ā	М	3.84	4.19



PIN CONFIGURATION 1. BASE 2. EMITTER

3. COLLECTOR

#### Packing Detail

<u>_</u>							
PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	GrWt
TO-3	100 pcs/pkt	1.3 kg/100 pcs	12.5" x 8" x 1.8"	0.1K	17" x 11.5" x 21"	2K	27.5 kgs



Continental Device India Pvt. Limited An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



#### **Customer Notes:**

#### **Component Disposal Instructions**

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.

2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

#### DISCLAIMER

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of Continental Device India Pvt. Limited C-120 Naraina Industrial Area, New Delhi 110 028, India. Telephone + 91-11-2579 6150, 4141 1112 Fax + 91-11-2579 5290, 4141 1119 email@cdil.com www.cdil.com CIN No. U32109DL1964PTC004291